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Positron annihilation lifetime (PAL) estimation of backscatter coefficients: ingredients for data correction

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ABSTRACT: Backscatter coefficients for a small variety of metals have been measured by PAL technique. "Source-surface" percentage contributions are presented for various specimens.

1. - INTRODUCTION

For a point, isotropic, heteroenergetic, single β^+ decay mode source, the fraction of positrons annihilating outside the bulk matrix of a typical sample sandwich configuration (Fig. 1) is, ignoring backscattering for the moment, presented as (1):

$$P(\alpha z) = 1 - \exp(-\alpha z) - \alpha z \operatorname{Ei}(-\alpha z) \quad [1]$$

where Ei is the exponential integral function, α is the absorption coefficient of the source-confining material, and z is the corresponding thickness.

PAL spectra involve contributing effects from source, foil and surfaces (2). Moreover, because of the backscattering process, reflected positrons may cross the source (imaginary) plane several times, contributing hence a non-negligible probability of absorption outside the homogeneous interior of the lattice under study (3). Therefore, αz should be replaced by $\alpha_t z_t$ (t for total) and [1] should be presented as the sum of contributions from all possible trajectories.

2. - MODEL

Replacing αz by $\alpha_t z_t$, neglecting backscattering from the foil, assuming no energy dependence for the backscatter coefficient R , and postulating that incident (on one side of the presumed symmetrical sandwich arrangement) and reflected (off that same side) positrons get implanted with the same profile, the complete functional form of [1] is then obtained by summing all contributions from the infinite series of reflections sketched in Fig 1. This yields:

$$Q = P + R(1-P) P' / [1-R(1-P')] \quad [2]$$

where $P = P(\alpha_t z_t)$ and $P' = P(2\alpha_t z_t)$, so that:

$$R = (Q - P) / (P' - P + Q - P'Q) \quad [3]$$

Integration over 2π solid angle (1.3) means even positrons emitted laterally with respect to the main axis are taken into account in the multiple backscattering process. Such a picture which may not reflect reality is likely to result in a little overestimation of the quantity under consideration. Now, suppressing the last (correction) term in [1], [3] becomes (for small $\alpha_k z_k$):

$$R = (Q - P) / (Q + P - 2PQ) \quad [4]$$

i.e. an expression for multiple backscattering along the direction of collimated positrons from sodium-22. Therefore, the true R is expected to be within the limits set by [3] and [4].

3. - RESULTS

The experimental set-up and the analysis procedure were as described in Ref 2. The "source-surface" lifetimes, seen in Fig. 2, distributed around the mean value 433 ps with no systematic trend.

R being Z-dependent (3), the percentage-contributions, I_r and I_s , for absorption in the foil ($0.5 \mu\text{m}$ Ni) and for annihilation in the "source-surface" sites, for each metal, were determined using (copper) the reference sample and scaling I_r/I_s to the ratio of the latter. This procedure was iterated until reaching steady values for I_r and I_s . Determination of R from [3] or [4] requires estimating P, i.e. $\alpha_k z_k$ and P', from data of a low-Z material, e.g. beryllium ($Z=4$). But owing to the strict safety measures accompanying use of the latter, kapton ($Z=4.2$) was chosen instead. In common with annealed metals, kapton displays a single lifetime component of some 380 ps. However, it may not involve surface-effects like these. So the idea was to measure the fraction of positrons annihilating in the foil with kapton as surrounding material and to deduce from the scaling above what would be roughly I_s for beryllium if one were to use the latter instead of kapton. Performing this, a value $P = 0.046 \pm 0.005$ was obtained. Resulting values of R from [3] and [4] are shown in Table 1. The uncertainty is typically 0.09. Comparison is made with results of MacKenzie *et al.* (3) from measurement geometry similar to that in here, and also with results of Arifov *et al.* (4) obtained for collimated positrons emitted by sodium-22. Agreement is reached within the uncertainty of the present measurements, validating therefore equation [2] for correcting experimental data.

To improve the measurements and to avoid doing a model-dependent determination of R, a series of experiments with configuration "metal-source-polystyrene", were carried out assuming no positron reflection from the polymeric part of this mixed sample arrangement. The spectrum characteristic of polystyrene, i.e. the reference one, was resolved in terms of three components for parapositronium decay, free annihilation, and pick-off annihilation of positrons bound in orthopositronium. The third component with lifetime 2 ns gave intensity $I_a = 40.25 \pm 0.08$. The desired backscatter coefficient R' was then extracted from the relative increase in the intensity I_s associated with the longlived, well-separated component due to pick-off annihilation in the polymeric counterpart of the selected metal. Results for R' are shown in table 1. The uncertainty is typically 0.004.

In most PAL investigations, people deal with defected specimens. Therefore, the influence of defects on I_s must be evaluated if one is to ensure proper correction to the experimental data. One expects the mean length of positrons diffusing to the surface of a layer to depend on the defect-state of the latter (2).

Table 2 contains values of I_s for various specimens. The observed behaviour of I_s seems compatible with what has been already pointed out to in Ref.2. I_s increases by some 0.5% for each added foil. More contribution is seen with the reduced density of dislocations in the "as-annealed" 2.5 μm additional Ni foil. Defected samples lead to some 1 % discrepancy in I_s with respect to anneal-cases.

4. - CONCLUSION

Extraction of coefficients for backscatter into 2π solid angle from "source-contributions" and comparison with commonly accepted relations (3,4) were just intended to validate equations [3] and [4] for correcting experimental data.

As expected, the model-independent determination of R gave results falling between values from Ref.3 and Ref.4, although most of these results are rather close to those of the former reference.

The influence of defects and/or of additional foils on the "source-surface" component is made evident.

"Source-surface" contributions determined for annealed samples have to be modified (by some 1%) before being used to correct the results for defected samples.

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Table 1.

Backscatter coefficients from "source-contributing-spectra" in conventional geometry "metal-source-metal", and from "bulk data" in mixed configuration "metal-source-polystyrene".

Element	Q	ΔQ	R [3]	R [4]	R (3)	R (4)	Is	R'
Al	0.070	0.001	0.24	0.22	0.235	0.194	0.2420	0.202
Fe	0.0807	0.0005	0.32	0.29	0.338	0.269	0.2674	0.328
Cu	0.0867	0.0005	0.36	0.33	0.354	0.283	0.2689	0.335
Zr	0.0917	0.0009	0.39	0.35	0.402	0.330		
Mo					0.409	0.337	0.2776	0.378
Ag	0.106	0.001	0.46	0.42	0.426	0.356	0.2821	0.401
Pt					0.501	0.452	0.3004	0.492
Au	0.1358	0.0007	0.56	0.53	0.503	0.455		

Table 2.

Source-surface" percentage contributions for various specimens.

(Source)-(foil)-(extra foil)-(sample) configuration	Is
(Na ²²)-(0.5 μ m Ni)-(none)-(annealed Pt)	4.8 $\pm$ 0.1
(Na ²²)-(0.5 μ m Ni)-(2.5 μ m deformed Ni)-(ann. Pt)	5.2 $\pm$ 0.1
(Na ²²)-(0.5 μ m Ni)-(2.5 μ m def-ann. Ni)-(ann. Pt)	5.6 $\pm$ 0.1
(Na ²²)-(0.5 μ m Ni)-(2.5 μ m def-ann-def. Ni)-(ann. Pt)	5.2 $\pm$ 0.1
(Na ²²)-(0.5 μ m Ni)-(2 x 2.5 μ m def. Ni)-(ann. Pt)	5.6 $\pm$ 0.1
(Na ²²)-(0.5 μ m Ni)-(none)-(Pt quenched "thermal vacancies")	3.6 $\pm$ 0.1
(Na ²²)-(0.5 μ m Ni)-(none)-(annealed Cu)	3.8 $\pm$ 0.1
(Na ²²)-(0.5 μ m Ni)-(none)-(deformed Cu at 10%)	3.0 $\pm$ 0.2
(Na ²²)-(0.5 μ m Ni)-(none)-(deformed Cu at 25%)	3.1 $\pm$ 0.2
(Na ²²)-(0.5 μ m Ni)-(none)-(deformed Cu at 50%)	2.8 $\pm$ 0.2
(Na ²²)-(0.5 μ m Ni)-(none)-(deformed Cu at 70%)	2.7 $\pm$ 0.2
(Na ²²)-(0.5 μ m Ni)-(none)-(annealed Ni)	3.7 $\pm$ 0.1
(Na ²²)-(0.5 μ m Ni)-(none)-(defected Ni)	3.1 $\pm$ 0.2
(Na ²²)-(0.5 μ m Ni)-(none)-(Ni containing krypton bubbles)	3.3 $\pm$ 0.3

Figure 1. Multiple backscattering process: positron absorption outside the bulk matrix of a typical sample sandwich configuration.

Figure 2. "Source-surface" lifetimes